

Lista publicațiilor: Vasiliev Ion Alexandru (8), Descărcări - 0, Vizualizări - 863

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2. Vasiliev, Ion. Shutov, Serghei. Amorphous, glassy and porous semiconductors: Photocapacitance relaxation in amorphous As₂Se₃ films. *Semiconductors*. 1999, nr. , 792-794. ISSN 1063-7826.
3. Iovu, Mihail. Sîrbu, Nicolae. Shutov, Serghei. Vasiliev, Ion. Rebeja, S.. Colomeico, Eduard. Popescu, Mihai A.. Sava, Florinel. Spectroscopical study of amorphous AsSe:Sn films. *Physica Status Solidi. A Applied Research*. 1999, nr. , 615-622. ISSN 0031-8965, ISSNe 1521-396X.
4. Iovu, Maria. Harea, Diana. Vasiliev, Ion. Colomeico, Eduard. Iovu, Mihail. Transient photocurrent in α -As₂Se₃ thin films with optical bias. *Proceedings of SPIE - The International Society for Optical Engineering*. Ediția 2, Vol.5972. 2005. Bellingham, Washington. Cavallioti. 1-8.
5. Iovu, Mihail. Vasiliev, Ion. Harea, Diana. Colomeico, Eduard. Photocurrent relaxation in As_xSe_{1-x} thin films: Compositional dependence. *Journal of Optoelectronics and Advanced Materials*. 2005, nr. , 2317-2322. ISSN 1454-4164.
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7. Iovu, Mihail. Vasiliev, Ion. Colomeico, Eduard. Spotiuc, Oleg. Photocapacitance relaxation and rigidity transition in Ge xAs xSe 1-2x amorphous films. *Journal of Optoelectronics and Advanced Materials*. 2011, nr. , 1478-1482. ISSN 1454-4164.
8. Iovu, Mihail. Vasiliev, Ion. Colomeico, Eduard. Emelianova, Evgenia. Arkhipov, Vladimir. Adriaenssens, Guy J.. Photocurrent relaxation in pure and Pr-doped a-As₂S₃ films. *Journal of Physics Condensed Matter*. 2004, nr. , 2949-2958. ISSN 0953-8984, ISSNe 1361-648X.

